



Institut luxembourgeois de la normalisation
de l'accréditation, de la sécurité et qualité
des produits et services

ILNAS-EN IEC 62969-3:2018

**Semiconductor devices -
Semiconductor interface for
automotive vehicles - Part 3: Shock
driven piezoelectric energy harvesting**

Halbleiterbauelemente -
Halbleiterschnittstelle für Automobile -
Teil 3: Stoßgeführtes piezoelektrisches
Energie-Harvesting bei Sensoren für

Dispositifs à semiconducteurs - Interface
à semiconducteurs pour les véhicules
automobiles - Partie 3: Récupération de
l'énergie piézoélectrique produite par les

06/2018



National Foreword

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ILNAS-EN IEC 62969-3:2018

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Semiconductor devices - Semiconductor interface for automotive vehicles - Part 3: Shock driven piezoelectric energy harvesting for automotive vehicle sensors (IEC 62969-3:2018)

Dispositifs à semiconducteurs - Interface à semiconducteurs pour les véhicules automobiles - Partie 3: Récupération de l'énergie piézoélectrique produite par les chocs pour les capteurs de véhicules automobiles (IEC 62969-3:2018)

Halbleiterbauelemente - Halbleiterschnittstelle für Automobile - Teil 3: Stoßgeführtes piezoelektrisches Energie-Harvesting bei Sensoren für Automobile (IEC 62969-3:2018)

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European Committee for Electrotechnical Standardization
Comité Européen de Normalisation Electrotechnique
Europäisches Komitee für Elektrotechnische Normung

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European foreword

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In the official version, for Bibliography, the following notes have to be added for the standards indicated:

IEC 62047-5:2011	NOTE	Harmonized as EN 62047-5:2011 (not modified).
IEC 62047-7:2011	NOTE	Harmonized as EN 62047-7:2011 (not modified).

Annex ZA (normative)

Normative references to international publications with their corresponding European publications

The following documents are referred to in the text in such a way that some or all of their content constitutes requirements of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

NOTE 1 Where an International Publication has been modified by common modifications, indicated by (mod), the relevant EN/HD applies.

NOTE 2 Up-to-date information on the latest versions of the European Standards listed in this annex is available here: www.cenelec.eu.

<u>Publication</u>	<u>Year</u>	<u>Title</u>	<u>EN/HD</u>	<u>Year</u>
IEC 60749-5	-	Semiconductor devices - Mechanical and climatic test methods - Part 5: Steady-state temperature humidity bias life test	EN 60749-5	-
IEC 60749-10	-	Semiconductor devices - Mechanical and climatic test methods - Part 10: Mechanical shock	EN 60749-10	-
IEC 60749-12	-	Semiconductor devices - Mechanical and climatic test methods - Part 12: Vibration, variable frequency	EN IEC 60749-12	-
IEC 62830-1	-	Semiconductor devices - Semiconductor devices for energy harvesting and generation - Part 1: Vibration based piezoelectric energy harvesting	-	-



INTERNATIONAL STANDARD

NORME INTERNATIONALE

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Part 3: Shock driven piezoelectric energy harvesting for automotive vehicle
sensors**

**Dispositifs à semiconducteurs – Interface à semiconducteurs pour les véhicules
automobiles –
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